# KRATOS GENERAL MICROWAVE Microwave Electronics Division

## Series SM Synthesizer FAST INDIRECT SYNTHESIZER WITH FREQUENCY MODULATION

### **Main Features**

High Speed: 1 µsec

Wide Frequency Range: 2 to 20 GHz

Frequency Modulation Span: 1 GHz

Analog & Digital Modulation Input

High Reliability



### **APPLICATIONS**

KRATOS General Microwave designed the series SM Fast Indirect Synthesizer, features Frequency Modulation while maintaining synthesizer operation. Designed for applications requiring a fast high performance synthesizer that is capable of Frequency Modulation (FM) while operating in the synthesizer mode. Designed for military and non-military applications, Series SM is ideal for applications such as Electronic Warfare (EW) systems, simulators, test systems, and signal generators. The enhanced performance characteristics place series SM in a class of its own and are unmatched by virtually all other synthesizers available today. In addition, the series SM allows the flexibility to customize performance characteristics to specific application requirements. For military applications this synthesizer requires option G09 to meet MIL STD.

### **MODEL SM6218 – Typical Modulation Spectrum**

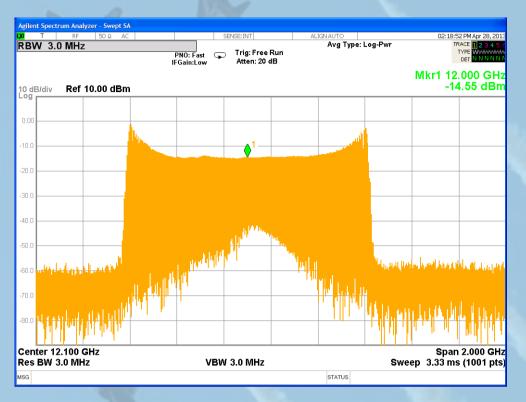


Fig. 1 - 1 GHz Modulation Spectrum using a Sine wave signal

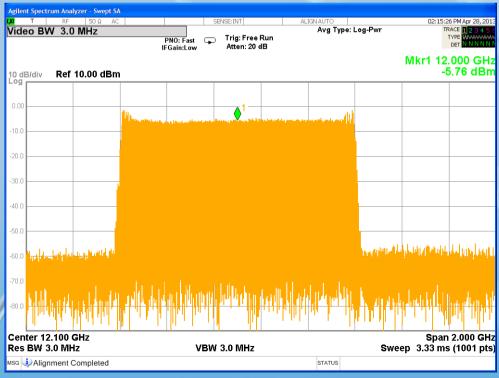


Fig. 2 - 1 GHz Modulation Spectrum using a Triangle signal

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PARAMETER		SPECIFICATION - MODEL			
		SM6218	SM6618	SM6220	
1	FREQUENCY RANGE(1) (GHz)	2 to 18	6 to 18	2 to 20	
2	ACCURACY	Same (PPM) as of the reference crystal oscillator			
3	FREQUENCY AGING	Same (PPM) as of the reference crystal oscillator			
4	OUTPUT POWER <sup>(1)</sup>				
4.1	Min. (dBm)	10			
4.2	Variation, over freq. at a given temp., max. (dB)	± 1.5			
4.3	Variation, over temperature, max. (dB)	±2.5			
5	SETTLING TIME, max. (µsec)	1			
6	SSB PHASE NOISE <sup>(2)</sup> , max (dBc/Hz)				
6.1	@ 100 Hz Offset	-75		-74	
6.2	@ 1 kHz Offset	-90		-89	
6.3	@ 10 kHz to 1 MHz Offset	-97		-96	
6.6	@ 10 MHz Offset	-100		-99	
7	HARMONICS, max (dBc)	-30 up to 24 GHz			
8	SUB-HARMONICS, max (dBc)	NA			
9	SPURIOUS, max (dBc)	-55		-54	
10	FREQUENCY CONTROL (PARALLEL)	18 BITS			
11	FREQ. STEP SIZE, nominal LSB (kHz)	100			
12	REFERENCE CRYSTAL OSCILLATOR - EXTERNAL <sup>(3)</sup>				
12.1	INPUT FREQUENCY, (MHz) <sup>(4)</sup>	100			
12.2	INPUT POWER, (dBm)	0 ±2			
13	MODULATION				
13.1	Bandwidth, (MHz)	DC to 10			
13.2	Frequency Deviation, min. (MHz)	± 500			
13.3	Sensitivity control (3 levels plus Mod. OFF)	2 BITS			
13.4	Digital Modulation Control	10 BITS			
13.4	Digital Sensitivity, nominal (MHz/bit)	1, 1/4, 1/16, Mod. OFF			
13.5	Analog Control, (V)	±1			
13.5	Analog Sensitivity, nominal (MHz/V)	500, 125, 31.25 Mod. OFF			
14	POWER SUPPLY REQUIREMENT, (V)	+12, -12, +5			
15	OPERATING TEMP. (°C)	-20 to +70			
16	OTHER ENVIRONMENTAL PARAMETERS	APPLICABLE FOR AIRBORNE APPLICATIONS			

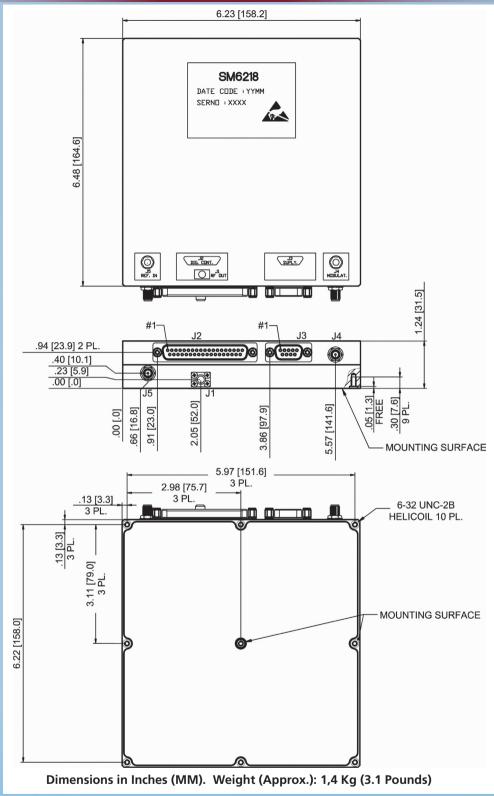
(1) Other values are available. Please contact Sales.

(2) With an external reference oscillator with the following phase noise dBc/Hz

@ 100 Hz Offset: -125 @ 1 kHz Offset: -140 @ 10 kHz Offset: -155 @ >100 kHz Offset: -160 (3) Internal Reference Oscillator is optional

(4) 10 MHz Optional

### **Dimensions and Outline**



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